www.ti.com

SN74CB3T3245 8-BIT FET BUS SWITCH 2.5-V/3.3-V LOW-VOLTAGE WITH 5-V-TOLERANT LEVEL SHIFTER

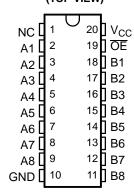
SCDS136-OCTOBER 2003-REVISED MARCH 2005

FEATURES

- Standard '245-Type Pinout
- Output Voltage Translation Tracks V_{CC}
- Supports Mixed-Mode Signal Operation on All Data I/O Ports
 - 5-V Input Down to 3.3-V Output Level Shift With 3.3-V V_{CC}
 - 5-V/3.3-V Input Down to 2.5-V Output Level
 Shift With 2.5-V V_{CC}
- 5-V-Tolerant I/Os With Device Powered Up or Powered Down
- Bidirectional Data Flow With Near-Zero Propagation Delay
- Low ON-State Resistance (r_{on}) Characteristics ($r_{on} = 5 \Omega \text{ Typ}$)
- Low Input/Output Capacitance Minimizes Loading (C_{io(OFF)} = 5 pF Typ)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I_{CC} = 40 μA Max)

- V_{CC} Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Supports Digital Applications: Level Translation, PCI Interface, USB Interface, Memory Interleaving, Bus Isolation
- Ideal for Low-Power Portable Equipment

DBQ, DGV, DW, OR PW PACKAGE (TOP VIEW)



NC - No internal connection

DESCRIPTION/ORDERING INFORMATION

The SN74CB3T3245 is a high-speed TTL-compatible FET bus switch with low ON-state resistance (r_{on}), allowing for minimal propagation delay. The device fully supports mixed-mode signal operation on all data I/O ports by providing voltage translation that tracks V_{CC} . The SN74CB3T3245 supports systems using 5-V TTL, 3.3-V LVTTL, and 2.5-V CMOS switching standards, as well as user-defined switching levels (see Figure 1).

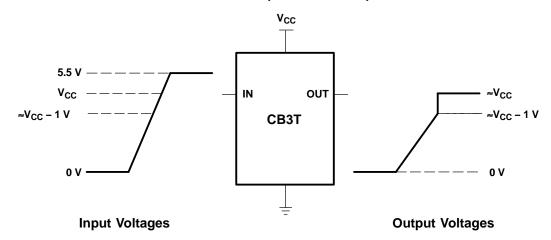


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



SCDS136-OCTOBER 2003-REVISED MARCH 2005

DESCRIPTION/ORDERING INFORMATION (CONTINUED)



NOTE A: If the input high-voltage (V_{IH}) level is greater than or equal to (V_{CC} – 1 V) and less than or equal to 5.5 V, then the output high-voltage (V_{OH}) level will be equal to approximately the V_{CC} voltage level.

Figure 1. Typical DC Voltage Translation Characteristics

The SN74CB3T3245 is an 8-bit bus switch with a single ouput-enable (\overline{OE}) input and a standard '245 pinout. When \overline{OE} is low, the 8-bit bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When \overline{OE} is high, the 8-bit bus switch is OFF, and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

T _A	PACKAG	E ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC – DW		SN74CB3T3245DW	CB3T3245
	SOIC - DVV	Tape and reel	SN74CB3T3245DWR	CD313243
–40°C to 85°C	SSOP (QSOP) – DBQ	Tape and reel	SN74CB3T3245DBQR	CB3T3245
-40 C to 65 C	TSSOP – PW	Tube	SN74CB3T3245PW	KS245
	1330P – PW	Tape and reel	SN74CB3T3245PWR	NS243
	TVSOP - DGV	Tape and reel	SN74CB3T3245DGVR	KS245

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

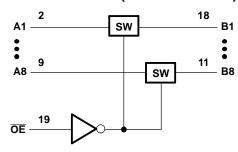
FUNCTION TABLE

INPUT OE	INPUT/OUTPUT A	FUNCTION
L	В	A port = B port
Н	Z	Disconnect

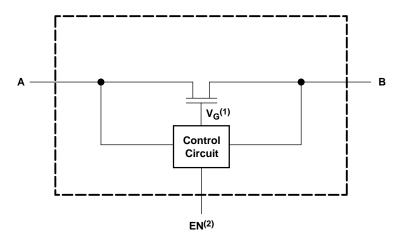


SCDS136-OCTOBER 2003-REVISED MARCH 2005

LOGIC DIAGRAM (POSITIVE LOGIC)



SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



- 1) Gate Voltage (V_G) is approximately equal to V_{CC} + V_{T} when the switch is ON and V_{I} > (V_{CC} + V_{T}).
- 2) EN is the internal enable signal applied to the switch.

SN74CB3T3245 8-BIT FET BUS SWITCH 2.5-V/3.3-V LOW-VOLTAGE WITH 5-V-TOLERANT LEVEL SHIFTER



SCDS136-OCTOBER 2003-REVISED MARCH 2005

Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾	-0.5	7	V	
V _{IN}	Control input voltage range ⁽²⁾⁽³⁾		-0.5	7	V
V _{I/O}	Switch I/O voltage range ⁽²⁾⁽³⁾⁽⁴⁾		-0.5	7	V
I _{IK}	Control input clamp current	V _{IN} < 0		-50	mA
I _{I/OK}	I/O port clamp current	V _{I/O} < 0		-50	mA
I _{I/O}	ON-state switch current ⁽⁵⁾		±128	mA	
	Continuous current through V _{CC} or GND			±100	mA
		DBQ package		68	
0	Dealings thermal impedance (6)	DGV package		92	°C/W
θ_{JA}	Package thermal impedance ⁽⁶⁾	DW package		58	-C/VV
		PW package		83	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- V_I and V_O are used to denote specific conditions for $V_{I/O}$.
- $I_{\rm I}$ and $I_{\rm O}$ are used to denote specific conditions for $I_{\rm I/O}$. The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT	
V _{CC}	Supply voltage		2.3	3.6	V	
V _{IH}	High-level control input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7	5.5	V	
	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2	5.5	V		
.,	Law law land and the line of well-and	V _{CC} = 2.3 V to 2.7 V	0	0.7	V	
V _{IL}	Low-level control input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	V	
V _{I/O}	Data input/output voltage		0	5.5	V	
T _A	Operating free-air temperature		-40	85	°C	

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

All voltages are with respect to ground unless otherwise specified.

The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.



SN74CB3T3245 8-BIT FET BUS SWITCH 2.5-V/3.3-V LOW-VOLTAGE WITH 5-V-TOLERANT LEVEL SHIFTER

SCDS136-OCTOBER 2003-REVISED MARCH 2005

Electrical Characteristics(1)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITION	MIN	TYP(2)	MAX	UNIT	
V _{IK}	V_{IK} $V_{CC} = 3 \text{ V}, I_I = -18 \text{ mA}$					-1.2	V
V _{OH}		See Figure 3 and Figure 4					
I _{IN}	Control inputs	V _{CC} = 3.6 V, V _{IN} = 3.6 V to 5.5 V or GND				±10	μΑ
	·		$V_{I} = V_{CC} - 0.7 \text{ V to } 5.5 \text{ V}$			±20	
I _I		$V_{CC} = 3.6 \text{ V}$, Switch ON, $V_{IN} = V_{CC}$ or GND	$V_{I} = 0.7 \text{ V to } V_{CC} - 0.7 \text{ V}$			-40	μΑ
			V _I = 0 to 0.7 V			±5	
I _{OZ} (3)		$V_{CC} = 3.6 \text{ V}, V_{O} = 0 \text{ to } 5.5 \text{ V}, V_{I} = 0, \text{ Switch}$	OFF, V _{IN} = V _{CC} or GND			±10	μΑ
l _{off}	$V_{CC} = 0, V_{O} = 0 \text{ to } 5.5 \text{ V}, V_{I} = 0,$					10	μΑ
		$V_{CC} = 3.6 \text{ V}, I_{I/O} = 0,$	$V_1 = V_{CC}$ or GND			40	^
Icc		Switch ON or OFF , $V_{IN} = V_{CC}$ or GND	V _I = 5.5 V			μA	
$\Delta I_{CC}^{(4)}$	Control inputs	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 \	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND			300	μΑ
C _{in}	Control inputs	$V_{CC} = 3.3 \text{ V}, V_{IN} = V_{CC} \text{ or GND}$			4		pF
C _{io(OFF)}	·	$V_{CC} = 3.3 \text{ V}, V_{I/O} = 5.5 \text{ V}, 3.3 \text{ V}, \text{ or GND, SV}$	vitch OFF, V _{IN} = V _{CC} or GND		5		pF
0		V 22 V Switch ON V V or CND	V _{I/O} = 5.5 V or 3.3 V	5			~F
$C_{io(ON)}$		$V_{CC} = 3.3 \text{ V}$, Switch ON, $V_{IN} = V_{CC}$ or GND	V _{I/O} = GND		13		pF
r _{on} ⁽⁵⁾		V 22V TVD V 25V V 0	I _O = 24 mA		5	8.5	
		$V_{CC} = 2.3 \text{ V}, \text{ TYP at } V_{CC} = 2.5 \text{ V}, V_{I} = 0$	I _O = 16 mA		5	8.5	0
		V 2VV 0	I _O = 64 mA		5	7	Ω
		$V_{CC} = 3 \text{ V}, V_{I} = 0$	I _O = 32 mA		5	7	

- V_{IN} and I_{IN} refer to control inputs. $V_I,\,V_O,\,I_I,$ and I_O refer to data pins. All typical values are at $V_{CC}=3.3$ V (unless otherwise noted), $T_A=25^{\circ}C.$ For I/O ports, the parameter I_{OZ} includes the input leakage current.

- This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND. Measured by the voltage drop between A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

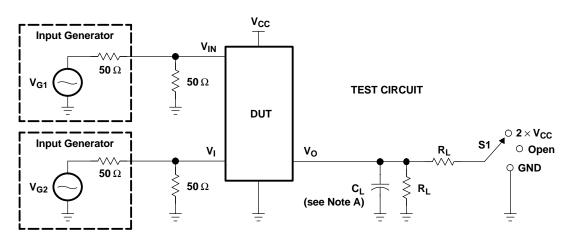
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
	(INPOT)	(001701)	MIN	MAX	MIN	MAX	
t _{pd} ⁽¹⁾	A or B	B or A		0.15		0.25	ns
t _{en}	ŌĒ	A or B	1	10.5	1	8	ns
t _{dis}	ŌE	A or B	1	5.5	1	7.5	ns

The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

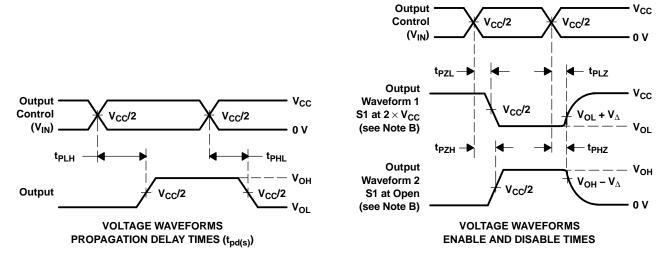




PARAMETER MEASUREMENT INFORMATION



TEST	V _{CC}	S1	R_{L}	VI	CL	$\mathbf{V}_{\!\Delta}$
t _{pd(s)}	2.5 V \pm 0.2 V	Open	500 Ω	3.6 V or GND	30 pF	
-pu(s)	3.3 V \pm 0.3 V	Open	500 Ω	5.5 V or GND	50 pF	
t _{PLZ} /t _{PZL}	2.5 V \pm 0.2 V	2×V _{CC}	500 Ω	GND	30 pF	0.15 V
'PLZ' 'PZL	3.3 V \pm 0.3 V	2×V _{CC}	500 Ω	GND	50 pF	0.3 V
4 /4	2.5 V \pm 0.2 V	Open	500 Ω	3.6 V	30 pF	0.15 V
t _{PHZ} /t _{PZH}	3.3 V \pm 0.3 V	Open	500 Ω	5.5 V	50 pF	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 2.5 ns. $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd(s)}. The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Test Circuit and Voltage Waveforms



SCDS136-OCTOBER 2003-REVISED MARCH 2005

TYPICAL CHARACTERISTICS

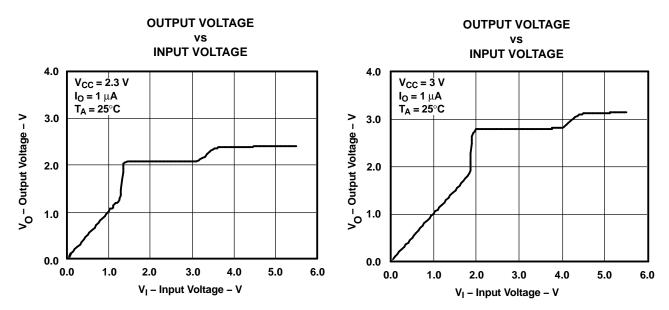
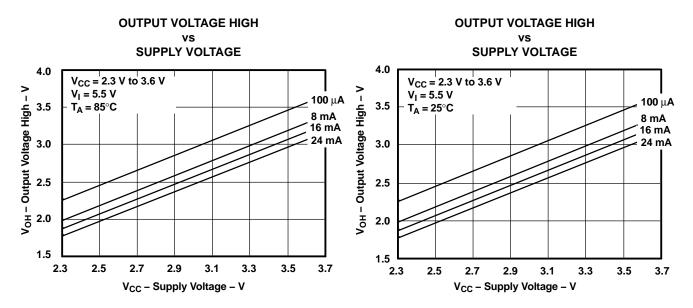


Figure 3. Data Output Voltage vs Data Input Voltage



TYPICAL CHARACTERISTICS



OUTPUT VOLTAGE HIGH vs

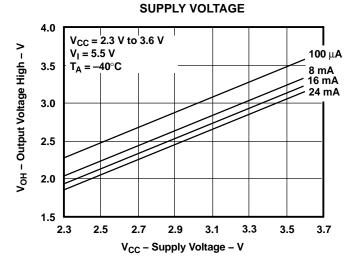


Figure 4. V_{OH} Values

PACKAGE OPTION ADDENDUM





PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
74CB3T3245DBQRE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
74CB3T3245DGVRE4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DBQR	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
SN74CB3T3245DGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



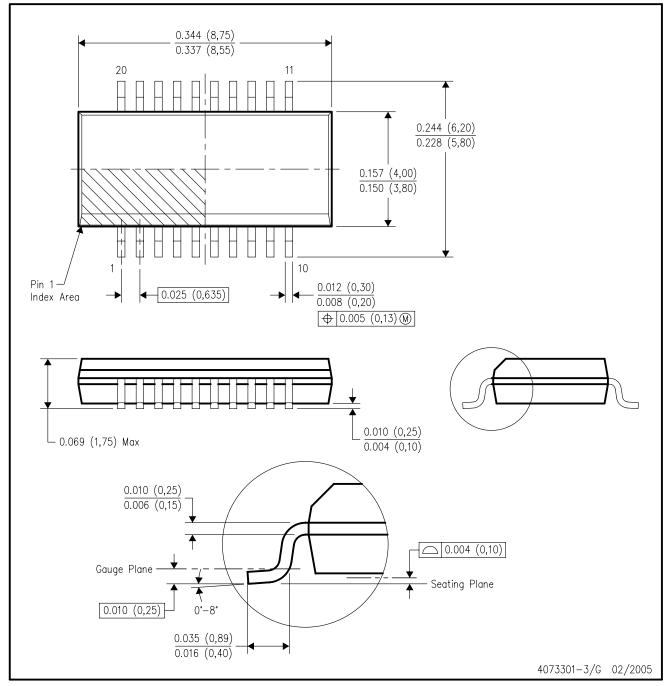
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DBQ (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

Copyright © 2005, Texas Instruments Incorporated